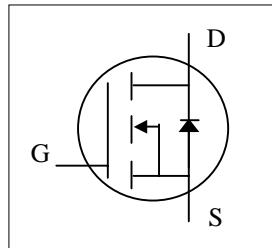
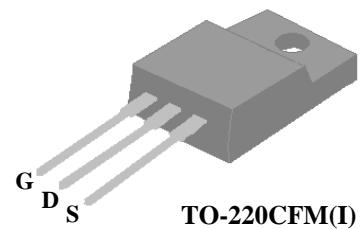




- ▼ 100% UIS Test
- ▼ Simple Drive Requirement
- ▼ Fast Switching Characteristic
- ▼ RoHS Compliant & Halogen-Free



BV_{DSS}	700V
$R_{DS(ON)}$	1.4 Ω
I_D^3	6A



Description

AP70AN1K4 series are from the innovated design and silicon process technology to achieve the lowest possible on-resistance and fast switching performance. It provides the designer with an extreme efficient device for use in a wide range of power applications.

The TO-220CFM package is widely preferred for all commercial-industrial through hole applications. The mold compound provides a high isolation voltage capability and low thermal resistance between the tab and the external heat-sink.

Absolute Maximum Ratings @ $T_j=25^\circ\text{C}$ (unless otherwise specified)

Symbol	Parameter	Rating	Units
V_{DS}	Drain-Source Voltage	700	V
V_{GS}	Gate-Source Voltage	± 30	V
$I_D @ T_C=25^\circ\text{C}$	Drain Current, $V_{GS} @ 10V^3$	6	A
I_{DM}	Pulsed Drain Current ¹	24	A
$P_D @ T_C=25^\circ\text{C}$	Total Power Dissipation	34.7	W
$P_D @ T_A=25^\circ\text{C}$	Total Power Dissipation	1.92	W
E_{AS}	Single Pulse Avalanche Energy ⁴	18	mJ
T_{STG}	Storage Temperature Range	-55 to 150	$^\circ\text{C}$
T_J	Operating Junction Temperature Range	-55 to 150	$^\circ\text{C}$

Thermal Data

Symbol	Parameter	Value	Units
Rthj-c	Maximum Thermal Resistance, Junction-case	3.6	$^\circ\text{C}/\text{W}$
Rthj-a	Maximum Thermal Resistance, Junction-ambient	65	$^\circ\text{C}/\text{W}$



AP70AN1K4I

Electrical Characteristics @T_j=25°C(unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250uA	700	-	-	V
R _{DS(ON)}	Static Drain-Source On-Resistance ²	V _{GS} =10V, I _D =3A	-	-	1.4	Ω
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250uA	2	-	4	V
g _{fs}	Forward Transconductance	V _{DS} =20V, I _D =3A	-	10	-	S
I _{DSS}	Drain-Source Leakage Current	V _{DS} =560V, V _{GS} =0V	-	-	100	uA
I _{GSS}	Gate-Source Leakage	V _{GS} =±30V, V _{DS} =0V	-	-	±1	uA
Q _g	Total Gate Charge	I _D =6A	-	29	46.4	nC
Q _{gs}	Gate-Source Charge	V _{DS} =560V	-	6	-	nC
Q _{gd}	Gate-Drain ("Miller") Charge	V _{GS} =10V	-	10	-	nC
t _{d(on)}	Turn-on Delay Time	V _{DD} =350V	-	16	-	ns
t _r	Rise Time	I _D =6A	-	20	-	ns
t _{d(off)}	Turn-off Delay Time	R _G =25Ω	-	86	-	ns
t _f	Fall Time	V _{GS} =10V	-	33	-	ns
C _{iss}	Input Capacitance	V _{GS} =0V	-	1250	2000	pF
C _{oss}	Output Capacitance	V _{DS} =100V	-	50	-	pF
C _{rss}	Reverse Transfer Capacitance	f=1.0MHz	-	7	-	pF
R _g	Gate Resistance	f=1.0MHz	-	2.2	4.4	Ω

Source-Drain Diode

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
V _{SD}	Forward On Voltage ²	I _S =3A, V _{GS} =0V	-	-	1.5	V
t _{rr}	Reverse Recovery Time	I _S =6A, V _{GS} =0V	-	410	-	ns
Q _{rr}	Reverse Recovery Charge	di/dt=100A/μs	-	2.5	-	uC

Notes:

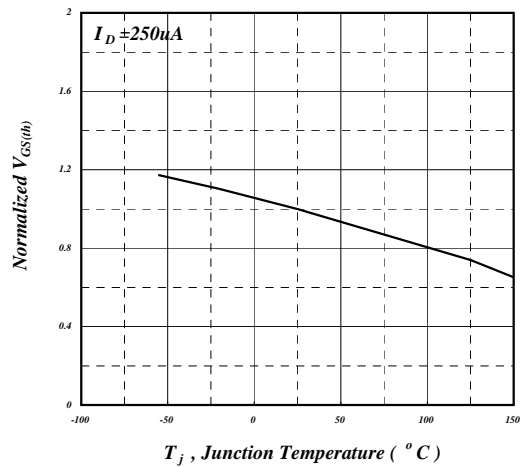
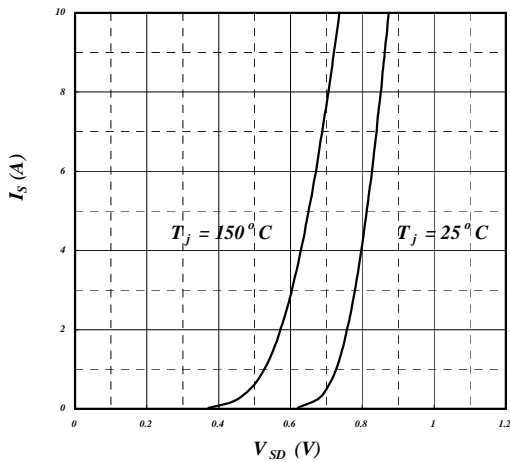
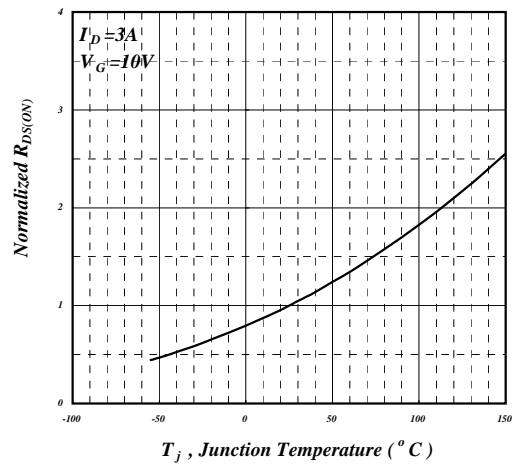
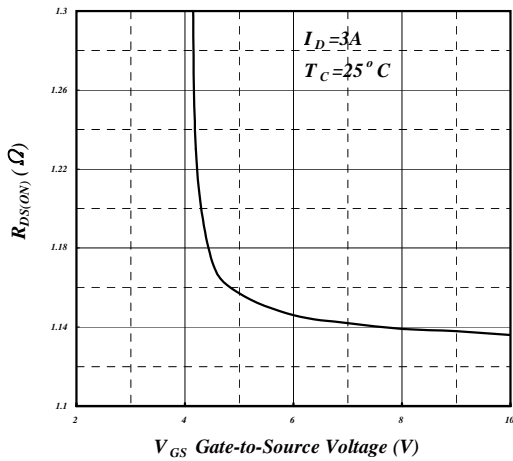
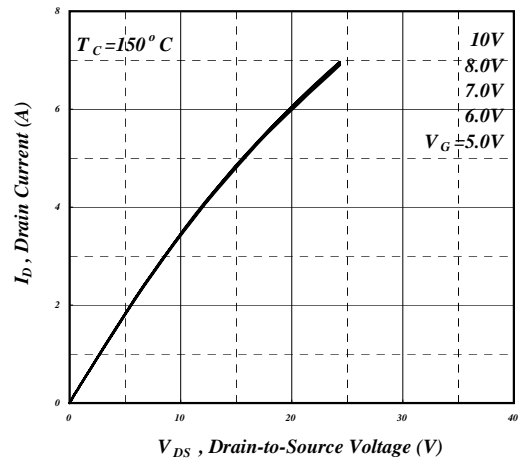
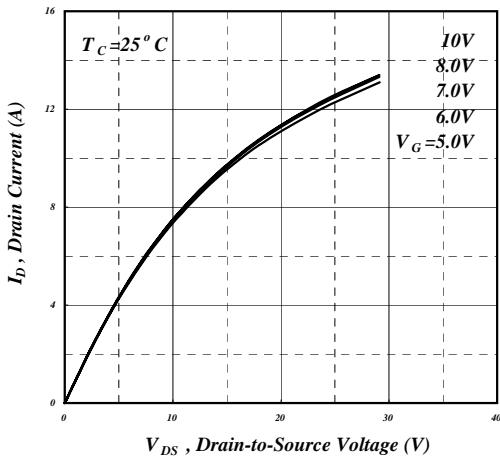
- 1.Pulse width limited by max. junction temperature.
- 2.Pulse test
- 3.Ensure that the junction temperature does not exceed T_{Jmax}.
- 4.Starting T_j=25°C , V_{DD}=90V , L=1mH , R_G=25Ω , V_{GS}=10V

THIS PRODUCT IS SENSITIVE TO ELECTROSTATIC DISCHARGE, PLEASE HANDLE WITH CAUTION.

USE OF THIS PRODUCT AS A CRITICAL COMPONENT IN LIFE SUPPORT OR OTHER SIMILAR SYSTEMS IS NOT AUTHORIZED.

APEC DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

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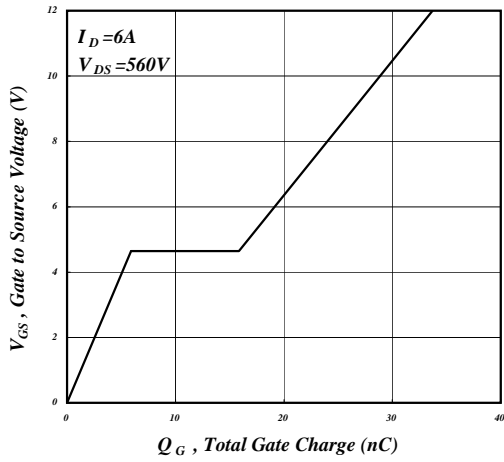


Fig 7. Gate Charge Characteristics

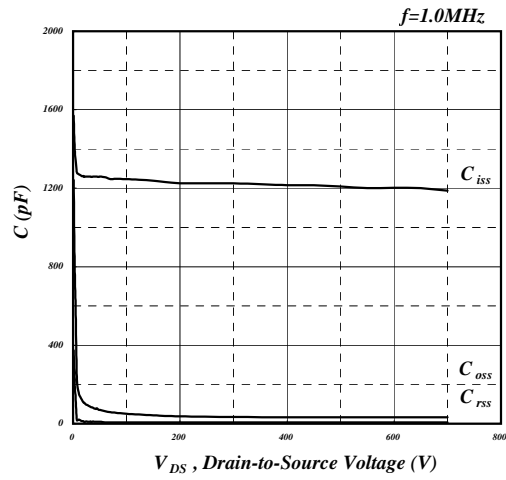


Fig 8. Typical Capacitance Characteristics

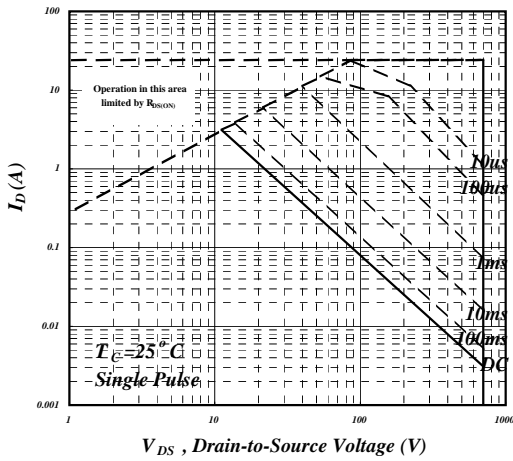


Fig 9. Maximum Safe Operating Area

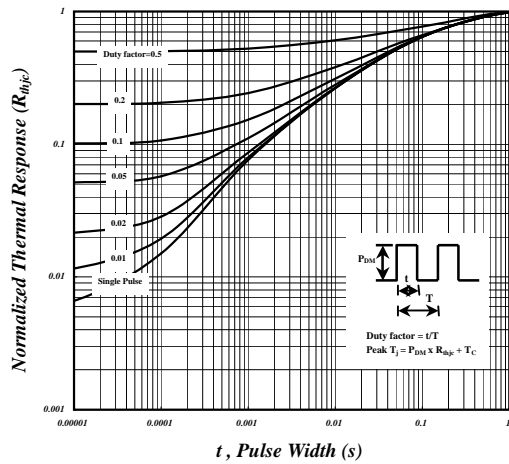


Fig 10. Effective Transient Thermal Impedance

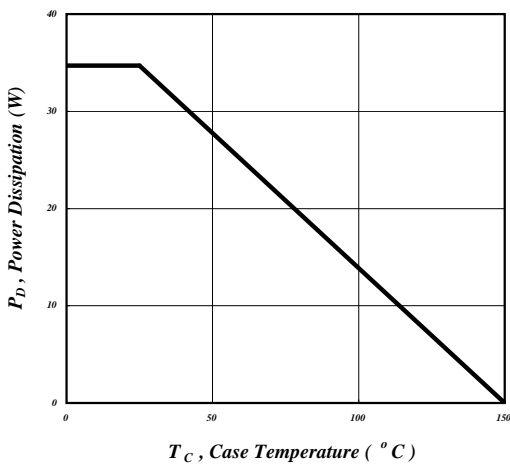


Fig 11. Total Power Dissipation

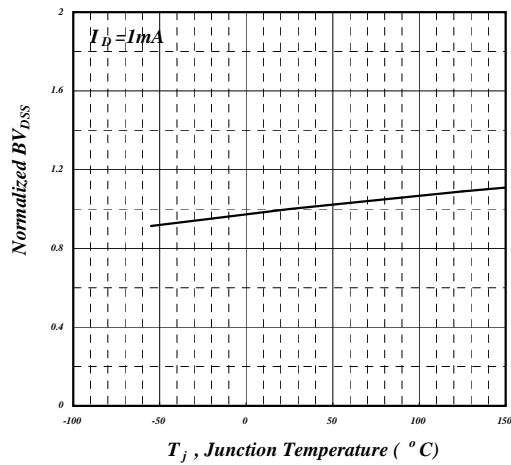
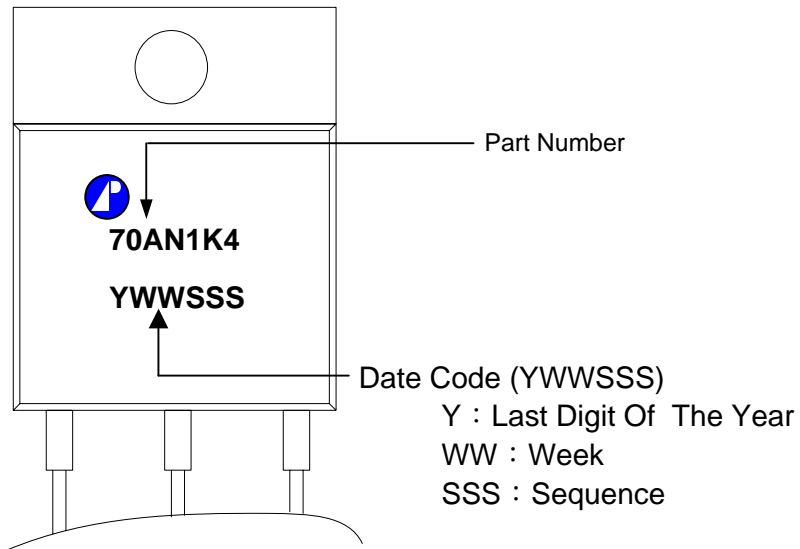


Fig 12. Normalized BV_{DSS} v.s. Junction Temperature

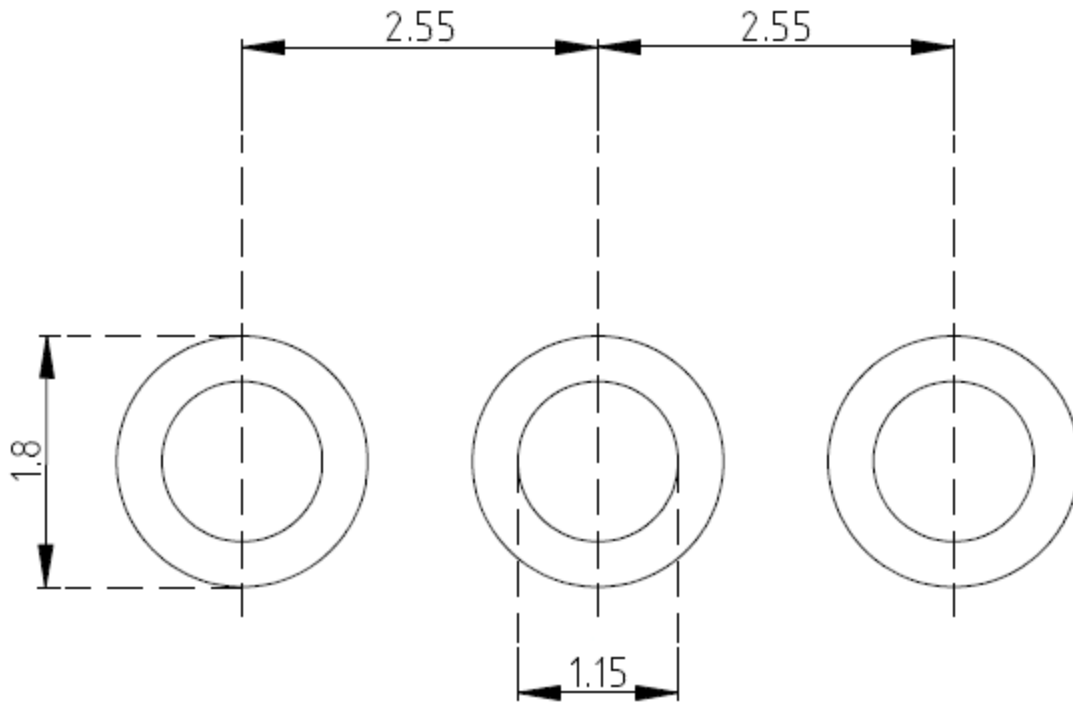


MARKING INFORMATION





TO-220CFM FOOTPRINT :



UNIT: mm